SLAS023D - FEBRUARY 1989 - REVISED JANUARY 2002

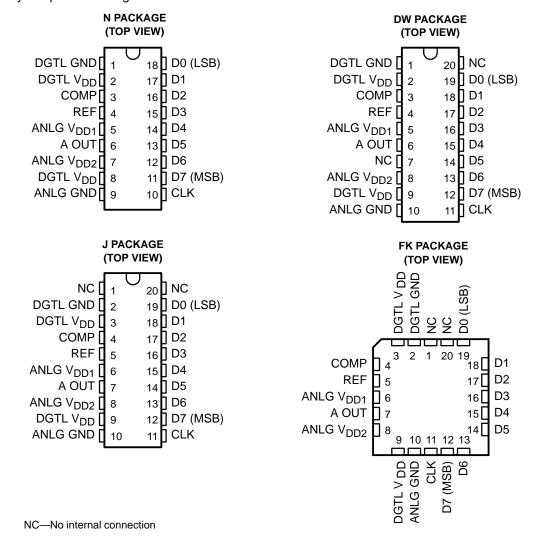
- 8-Bit Resolution
- ±0.2% Linearity
- **Maximum Conversion Rate** 30 MHz Typ 20 MHz Min
- **Analog Output Voltage Range**  $V_{DD}$  to  $V_{DD} - 1 V$

- TTL Digital Input Voltage
- 5-V Single Power-Supply Operation
- Low Power Consumption . . . 80 mW Typ
- Interchangeable With Fujitsu MB40778

### description

The TLC5602x devices are low-power, ultra-high-speed video, digital-to-analog converters that use the LinEPIC™ 1-µm CMOS process. The TLC5602x converts digital signals to analog signals at a sampling rate of dc to 20 MHz. Because of high-speed operation, the TLC5602x devices are suitable for digital video applications such as digital television, video processing with a computer, and radar-signal processing.

The TLC5602C is characterized for operation from 0°C to 70°C. The TLC5602M is characterized over the full military temperature range of -55°C to 125°C.



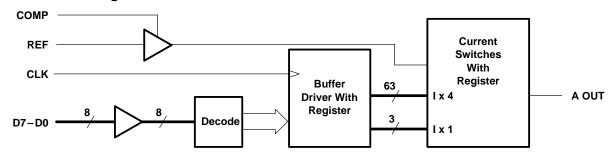
LinEPIC is a trademark of Texas Instruments Incorporated.



### **AVAILABLE OPTIONS**

PACKAGE									
TA	WIDE-BODY SMALL OUTLINE (DW)	CERAMIC CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)					
0°C to 70°C	TLC5602CDW			TLC5602CN					
-55°C to 125°C		TLC5602MFK	TLC5602MJ						

## functional block diagram

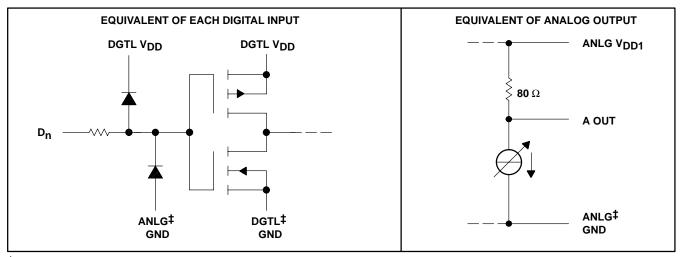


### **FUNCTION TABLE**

STEP			DI	GITAL	INPUT	s			OUTPUT	
SIEF	D7	D6	D5	D4	D3	D2	D1	D0	VOLTAGE <sup>†</sup>	
0	L	L	L	L	L	L	L	L	3.980 V	
1	L	L	L	L	L	L	L	Н	3.984 V	
				1		I				I
127	L	Н	Н	Н	Н	Н	Н	Н	4.488 V	
128	Н	L	L	L	L	L	L	L	4.492 V	
129	Н	L	L	L	L	L	L	Н	4.496 V	
									1	
254	Н	Н	Н	Н	Н	Н	Н	L	4.996 V	
255	Н	Н	Н	Н	Н	Н	Н	Н	5.000 V	

 $\dagger$  V<sub>DD</sub> = 5 V and V<sub>ref</sub> = 4.02 V

### schematics of equivalent input and output



<sup>‡</sup> ANLG GND and DGTL GND do not connect internally and should be tied together as close to the device terminals as possible.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, ANLG V <sub>DD</sub> , DGTL V <sub>DD</sub>	0.5 V to 7 V
Digital input voltage range, V <sub>I</sub>	0.5 V to 7 V
Analog reference voltage range, V <sub>ref</sub>	
Operating free-air temperature range, T <sub>A</sub> : TLC5602C	0°C to 70°C
TLC5602M	–55°C to 125°C
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## recommended operating conditions

			MIN	NOM	MAX	UNIT
Supply voltage, V <sub>DD</sub>			4.75	5	5.25	V
Analog reference voltage, V <sub>ref</sub>			3.8	4	4.2	V
High-level input voltage, V <sub>IH</sub>			2			V
Low-level input voltage, V <sub>IL</sub>			8.0	V		
Pulse duration, CLK high or low, tw	25			ns		
Setup time, data before CLK↑, t <sub>SU</sub>	Setup time, data before CLK↑, t <sub>SU</sub>					ns
Hold time, data after CLK↑, th	old time, data after CLK↑, th 12.5					ns
Phase compensation capacitance, Ccor	np (see Note 1)		1			μF
Load resistance, R <sub>L</sub>			75			Ω
Operating free air temperature Te	TLC5602C		0		70	°C
Operating free-air temperature, TA	TLC5602M		-55		125	ر

NOTE 1: The phase compensation capacitor should be connected between COMP and ANLG GND.



## TLC5602C, TLC5602M VIDEO 8-BIT DIGITAL-TO-ANALOG CONVERTERS

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# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER		TES	ST CONDITIONS		MIN	TYP‡	MAX	UNIT
lн	High-level input current	Digital	V <sub>I</sub> = 5 V					±1	μΑ
I <sub>I</sub> L	Low-level input current	inputs	V <sub>I</sub> = 0 V					±1	μΑ
I <sub>ref</sub>	Input reference current		V <sub>ref</sub> = 4 V			10	μΑ		
$V_{FS}$	Full-scale analog output vo	oltage	$V_{DD} = 5 V$ ,	V <sub>DD</sub> -15	$V_{DD}$	V <sub>DD</sub> +15	mV		
			.,,	., ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	TLC5602C	3.919	3.98	4.042	
Vzs	Zero-scale analog output v	oltage/	$V_{DD} = 5 \text{ V},$ $V_{ref} = 4.02 \text{ V},$ $T_A = \text{full range}$	$V_{ref} = 4.02 V,$	TLC5602M	3.919	3.98	4.042	V
			TA = Tall Tallges		TLC5602M	3.919	3.98	4.062	1
_	Output registeres		T <sub>A</sub> = 25°C		TLC5602C	60	80	120	Ω
r <sub>O</sub>	Output resistance		T <sub>A</sub> = full range§ TLC5602M			60	00	120	52
Ci	Input capacitance		$f_{Clock} = 1 \text{ MHz},  T_A = 25^{\circ}\text{C}$				15	·	pF
$I_{DD}$	Supply current		f <sub>clock</sub> = 20 MHz,	$V_{ref} = V_{DD} - 0.9$	95 V		16	25	mA

<sup>‡</sup> All typical values are at  $V_{DD} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ .

# operating characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONE	DITIONS	MIN	TYP†	MAX	UNIT
		T <sub>A</sub> = full range‡	TLC5602C			±0.2%	
E <sub>L(adj)</sub>	Linearity error, best-straight-line	T <sub>A</sub> = 25°C	TLC5602M			±0.2%	
		T <sub>A</sub> = full range‡	1 LC3002IVI			±0.4%	
EL	Linearity error, end point				±0.15%		
E <sub>D</sub>	Linearity error, differential					±0.2%	
G <sub>diff</sub>	Differential gain	NTSC 40-IRE mod	ulated ramp,		0.7%		
fdiff	Differential phase	$f_{clock} = 14.3 \text{ MHz}, Z_L \ge 75 \text{ k}\Omega$			0.4°		
t <sub>pd</sub>	Propagation delay time, CLK to analog output	C <sub>L</sub> = 10 pF			25		ns
t <sub>S</sub>	Settling time to within 1/2 LSB	C <sub>L</sub> = 10 pF			30	•	ns

<sup>†</sup> All typical values are at  $V_{DD} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ .



<sup>§</sup> Full range for the TLC5602C is 0°C to 70°C, and full range for the TLC5602M is –55°C to 125°C.

<sup>‡</sup> Full range for the TLC5602C is 0°C to 70°C, and full range for the TLC5602M is -55°C to 125°C.

### PARAMETER MEASUREMENT INFORMATION

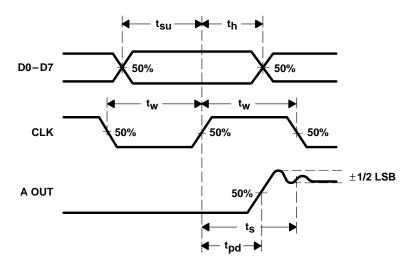
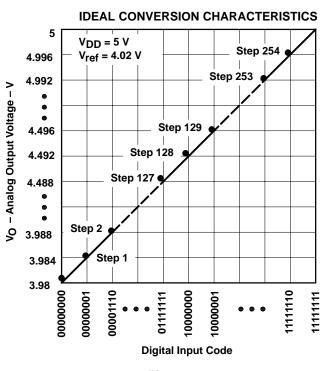


Figure 1. Voltage Waveforms

### TYPICAL CHARACTERISTICS



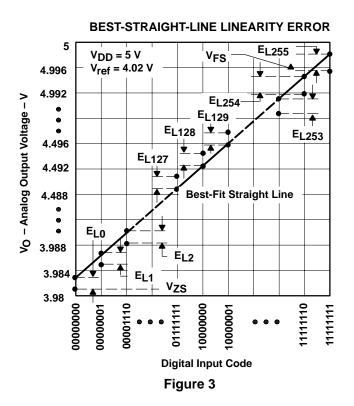


**ZERO-SCALE OUTPUT VOLTAGE** 

### FREE-AIR TEMPERATURE 4.02 $V_{DD} = 5 V$ V<sub>ref</sub> = 4.02 V 4.01 Vzs - Zero-Scale Output Voltage - V See Note A 3.99 3.98 3.97 3.96 3.95 3.94 3.93 - 55 - 35 - 15 5 25 45 65 85 105 125 $T_A$ – Free-Air Temperature – $^{\circ}$ C

NOTE A: V<sub>ref</sub> is relative to ANLG GND. V<sub>DD</sub> is the voltage between ANLG V<sub>DD</sub> and DGTL V<sub>DD</sub> tied together and ANLG GND and DGTL GND tied together.

Figure 4



### OUTPUT RESISTANCE vs FREE-AIR TEMPERATURE

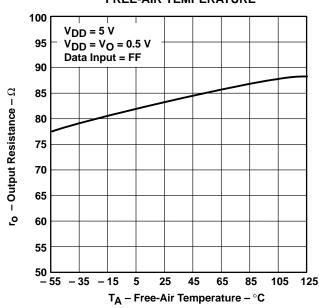
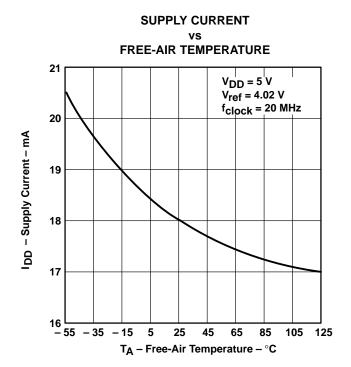


Figure 5



**ZERO-SCALE OUTPUT VOLTAGE** 

## **TYPICAL CHARACTERISTICS**



## **REFERENCE VOLTAGE** $V_{DD} = 5 \text{ V}$ $T_A = 25^{\circ}C$ 4.8 See Note A Vzs - Zero-Scale Output Voltage - V 4.6 4.4 4.2 3.8

NOTE A:  $V_{ref}$  is relative to ANLG GND.  $V_{DD}$  is the voltage between ANLG  $V_{DD}$  and DGTL  $V_{DD}$  tied together and ANLG GND and DGTL GND tied together.

4.2

V<sub>ref</sub> - Reference Voltage - V

4.4

4.6

4.8

5

4

Figure 6 Figure 7

3.6

3.4 3.4

3.6

3.8

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### APPLICATION INFORMATION

The following design recommendations benefit the TLC5602 user:

- Physically separate and shield external analog and digital circuitry as much as possible to reduce system noise.
- Use RF breadboarding or RF printed-circuit-board (PCB) techniques throughout the evaluation and production process.
- Since ANLG GND and DGTL GND are not connected internally, these terminals need to be connected
  externally. With breadboards, these ground lines should connect to the power-supply ground through
  separate leads with proper supply bypassing. A good method is to use a separate twisted pair for the analog
  and digital supply lines to minimize noise pickup.
  - Use wide ground leads or a ground plane on the PCB layouts to minimize parasitic inductance and resistance. The ground plane is the better choice for noise reduction.
- ANLG V<sub>DD</sub> and DGTL V<sub>DD</sub> are also separated internally, so they must connect externally. These external
  PCB leads should also be made as wide as possible. Place a ferrite bead or equivalent inductance in series
  with ANLG V<sub>DD</sub> and the decoupling capacitor as close to the device terminals as possible before the ANLG
  V<sub>DD</sub> and DGTL V<sub>DD</sub> leads are connected together on the board.
- Decouple ANLG V<sub>DD</sub> to ANLG GND and DGTL V<sub>DD</sub> to DGTL GND with a 1-μF and 0.01-μF capacitor, respectively, as close as possible to the appropriate device terminals. A ceramic chip capacitor is recommended for the 0.01-μF capacitor.
- Connect the phase compensation capacitor between COMP and ANLG GND with as short a lead-in as possible.
- The no-connection (NC) terminals on the small-outline package should be connected to ANLG GND.
- Shield ANLG V<sub>DD</sub>, ANLG GND, and A OUT from the high-frequency terminals CLK and D7-D0. Place ANLG GND traces on both sides of the A OUT trace on the PCB.





## PACKAGE OPTION ADDENDUM

10-Dec-2020

### PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLC5602CDW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC5602C	Samples
TLC5602CDWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC5602C	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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10-Dec-2020

## **PACKAGE MATERIALS INFORMATION**

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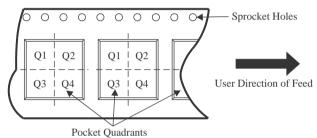
### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC5602CDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

**PACKAGE MATERIALS INFORMATION** 

www.ti.com 5-Dec-2023



### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC5602CDWR	SOIC	DW	20	2000	535.4	167.6	48.3

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 5-Dec-2023

### **TUBE**



### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLC5602CDW	DW	SOIC	20	25	506.98	12.7	4826	6.6



SOIC



### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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